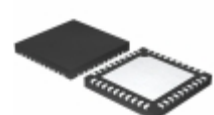


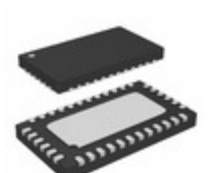

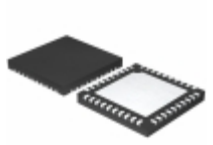
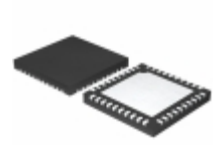
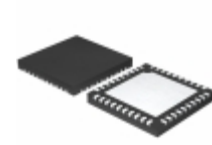
	<h2>SI3453DV-T1-GE3</h2>
	<p><b>Hersteller-Teilenummer:</b> SI3453DV-T1-GE3</p> <p><b>Hersteller / Marke:</b> Electro-Films (EFI) / Vishay</p> <p><b>Teil der Beschreibung:</b> MOSFET P-CHANNEL 30V 3.4A 6TSOP</p> <p><b>Datenblätter:</b>  SI3453DV-T1-GE3.pdf</p> <p><b>RoHs Status:</b></p> <p><b>Lagerzustand:</b> New original, 84265 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	SI3453DV-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET P-CHANNEL 30V 3.4A 6TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	84265 pcs Stock
detaillierte Beschreibung	P-Channel 30V 3.4A (Tc) 3W (Tc) Surface Mount 6-
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	3W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3.4A (Tc)
Rds On (Max) @ Id, Vgs	165 mOhm @ 2.5A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	6.8nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	155pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)

SI3453DV-T1-GE3 ist neu im Original, Suche SI3453DV-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3453DV-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI3453DV-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>SI3453D-B02-GMR</b> Energy Micro (Silicon Labs) IC POE PSE PORT CTRLR QUAD 40QFN</p>	 <p><b>SI3453DV-T1-E3</b> Son Son TSOP-6</p>	 <p><b>SI3454-KIT</b> Energy Micro (Silicon Labs) EVAL KIT FOR SI3454 POE CTRLR</p>	 <p><b>SI3454-B01-IM</b> Energy Micro (Silicon Labs) IC POE PSE 4 PORT 802.3AT 38QFN</p>
 <p><b>SI3453DV-T1-GE3</b> VISHAY VISHAY SOT-23-6</p>	 <p><b>SI3453C-B02-GMR</b> Energy Micro (Silicon Labs) IC POE PSE PORT CTRLR QUAD 40QFN</p>	 <p><b>SI3453D-B02-GM</b> Energy Micro (Silicon Labs) IC POE PSE PORT CTRLR QUAD 40QFN</p>	 <p><b>SI3453D-B01-GM</b> Energy Micro (Silicon Labs) IC POE CONTROLLER MIDSPAN 40QFN</p>

### heiße Teile

Mehr

SI3447BDV	SI3447BDV-T1	SI3447BDV-T1-E3	SI3447BDV-T1-E3	SI3447BDV-T1-GE3
SI3447BDV-T1-GE3	SI3447BDV-TI-GE3	SI3447CDV-T1	SI3447CDV-T1-E3	SI3447CDV-T1-GE3
SI3447CDV-T1-GE3	SI3447CDV-T1-GE3	SI3447DV	SI3447DV-NL	SI3447DV-T1
SI3447DV-T1-E3	SI3447DV-T1-GE3	SI3448DV	SI3448DV-T1-E3	SI3451DV-T1-E3
SI3451DV-T1-E3	SI3451DV-T1-GE3	SI3451DV-T1-GE3	SI3452DV-T1-E3	SI3453DV-T1-GE3
SI3453DV-T5-GE3	SI3454ADV-T1	SI3454ADV-T1-E3	SI3454ADV-T1-E3	SI3454ADV-T1-GE3
SI3454ADV-T1-GE3	SI3454CDV-T1-GE3	SI3454CDV-T1-GE3	SI3454DV-NL	SI3454DV-T1
SI3454DV-T1-E3	SI3455ADV-T1-E3	SI3455ADV-T1-E3	SI3455ADV-T1-GE3	SI3455ADV-T1-GE3
SI3455DV-NL	SI3455DV-T1-E3	SI3455DV-T1-GE3	SI3456-C02-GU	SI3456-E04-GU
SI3456BD-T1-E3	SI3456BDV-T1	SI3456BDV-T1-E3	SI3456BDV-T1-E3	SI3456BDV-T1-GE3

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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